Crystal structure and ferroelectric properties of $A Bi_2 Ta_2 O_9$ (A = Ca, Sr, and Ba)

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Crystal structures and ferroelectric properties of a series of Bi-layered compounds, $CaBi_2Ta_2O_9$, $SrBi_2Ta_2O_9$, and $BaBi_2Ta_2O_9$, were investigated. The structures of $CaBi_2Ta_2O_9$ and $SrBi_2Ta_2O_9$ are orthorhombic, while that of $BaBi_2Ta_2O_9$ is pseudotetragonal on the macroscopic scale but consists of microdomains with orthorhombic distortion. The ferroelectric Curie temperature of $CaBi_2Ta_2O_9$ was over 600 °C, and that of $SrBi_2Ta_2O_9$ was over 300 °C. $BaBi_2Ta_2O_9$, in contrast, showed relaxor-type ferroelectric behavior; that is, in the plot of temperature dependence of dielectric constant, a broad peak appeared around 60 °C. As the size of the *A*-site cation decreases from Ba^{2+} to Ca^{2+} , the lattice mismatch between TaO_2 and AO planes in the perovskite-type unit of ATa_2O_7 increases and the structural distortion becomes more pronounced. This distortion leads to the higher Curie temperature and the larger spontaneous ferroelectric polarization.

I. INTRODUCTION

In recent years ferroelectric thin films have attracted a lot of attention for use in nonvolatile memory applications (ferroelectric random access memories). Bi-layered compounds as well as $PbZr_{1-x}Ti_xO_3$ perovskites are leading candidates for such devices and have been extensively studied. These so-called Aurivillius compounds were discovered in the late 40's,¹⁻³ and their basic structural and ferroelectric properties were studied in the early 60's.⁴ Among these compounds, ferroelectric SrBi₂Ta₂O₉ has been the most intensively studied for use in memory devices due to its fatiguefree nature.^{5,6}

The crystal structure of $\text{SrBi}_2\text{Ta}_2\text{O}_9$ consists of Bi_2O_2 layers and perovskite-type SrTa_2O_7 units with double TaO_6 octahedral layers. And it was studied by using neutron and electron diffraction, which revealed orthorhombic distortion with space group $A2_1am$.^{7,8} The structural distortion with this noncentrosymmetric space group is responsible for the displacive-type ferroelectric behavior of the compound; that is, atomic displacements along the *a* axis from corresponding positions in the parent tetragonal (*I*4/*mmm*) structure cause spontaneous ferroelectric polarization.

We previously studied crystal structures of stoichiometric $SrBi_2Ta_2O_9$ and off-stoichiometric $Sr_{0.8}Bi_{2.2}Ta_2O_9$ ferroelectric materials by neutron powder diffraction and revealed that cation substitution at a Sr site significantly influences ferroelectric properties.⁹ In the off-stoichiometric sample, both Bi substitution and cation vacancies exist at the Sr site, and chemical composition of the material is $(Sr_{0.82}Bi_{0.12})Bi_2Ta_2O_{9.0}$. The substitution of smaller Bi^{3+} for Sr^{2+} increases structural distortion, which leads to larger ferroelectric polarization and higher ferroelectric Curie temperature. This finding suggested that the size of the *A*-site cation strongly affects ferroelectric properties.

In the present work, we have analyzed the crystal struc-

tures of a series of Bi-layered compounds with different *A*-site cations, i.e., $ABi_2Ta_2O_9$ (A=Ca, Sr, and Ba). Highresolution neutron powder diffraction can reveal the detailed crystal structures of such displacive-type ferroelectric materials. We are thus able to understand the relationships between crystal structures and ferroelectric properties. Consequently, we have found that the structural distortion increases with decreasing size of the *A*-site cation and that ferroelectric properties are strongly affected by structural distortion.

II. EXPERIMENTS

Powder samples of CaBi₂Ta₂O₉, SrBi₂Ta₂O₉, and BaBi₂Ta₂O₉ were prepared by solid-state reaction. Mixtures of appropriate amounts of CaCO₃, SrCO₃, BaCO₃, Bi₂O₃, and Ta₂O₅ were sintered at 1000-1370 °C for 12-30 h in air. The samples were confirmed to be single phases by both x-ray and neutron diffraction. Capacitance of the disk-shaped samples was measured at temperatures from -180 to $600 \,^{\circ}\text{C}$ by using a conventional LCR meter with a frequency of 1, 10, and 100 kHz. The P (polarization)-E (electric field) hysteresis loop was measured at room temperature by a Sawyer-Tower circuit. Time-of-flight neutron powder diffraction data were collected at room temperature on the Vega diffractometer at KENS.¹⁰ Structural parameters were refined by the Rietveld method with the program RIETAN-98T.¹¹ A structural change of BaBi₂Ta₂O₉ at low temperature was investigated by x-ray diffraction. The measurements were carried out at temperatures from room temperature down to -250 °C by using θ -2 θ goniometer equipped with a refrigerator.

III. RESULTS

The x-ray and neutron-diffraction patterns showed that structures of $CaBi_2Ta_2O_9$ and $SrBi_2Ta_2O_9$ are orthorhombic

6559



FIG. 1. Neutron-diffraction patterns of $ABi_2Ta_2O_9$ (A=Ca, Sr, and Ba) and the Rietveld refinement profiles. The observed diffraction data are shown as plus marks, and the calculated profile as a solid line. Tick marks below the profile mark the positions of allowed reflections. Differences between the observed and the calculated intensities are shown at the bottom.

with space group $A2_1am$. No anomalous occupancies were observed at any of the sites, which provides evidence for stoichiometric compositions as expected from the nominal ones. However, structural refinement of BaBi₂Ta₂O₉ with the orthorhombic $A2_1am$ space group was unsuccessful. Attempts to refine structural parameters on the basis of the orthorhombic cell resulted in convergence to a pseudotetragonal $(a \approx b)$ structure. In addition, characteristic orthorhombic reflections such as 1 2 2 ($d \approx 2.41$ Å) and 5 1 2 $(d \approx 2.20 \text{ Å})$ are extinct in BaBi₂Ta₂O₉. Since these reflections are not allowed in the tetragonal symmetry, the diffraction data support the pseudotetragonal structure of BaBi₂Ta₂O₉. Then, structural parameters of BaBi₂Ta₂O₉ were refined according to a pseudotetragonal cell with space group I4/mmm. Observed reflections of BaBi₂Ta₂O₉ showed considerable anisotropic broadening, which was corrected by using partial profile relaxation.¹¹ Figure 1 shows the neutron powder diffraction patterns at room temperature and Rietveld refinement profiles for the three samples. Tables I, II, and III list the refined structural parameters of each compound.

The thermal site parameter of the Bi in BaBi₂Ta₂O₉ ($B_{eq} = 2.70 \text{ Å}^2$) is much larger than those in $CaBi_2Ta_2O_9$ (1.00 Å²) and $SrBi_2Ta_2O_9$ (1.54 Å²). This result might indicate a mutual substitution between the Ba and Bi ions, as reported in isostructural BaBi₂Nb₂O₉.¹² The refinement according to a model with Ba and Bi substitutions at the Bi and Ba sites, respectively, slightly lowered R_{wp} from 4.79 to 4.67%, but the refined thermal parameter of the Bi site increased from 2.70 to 2.90 Å². Thus, we could not confirm such substitution. Because the resulting positional parameters of BaBi₂Ta₂O₉ were practically identical in both models, we focus only on positional parameters of $BaBi_2Ta_2O_9$ in the present study.

Figure 2 shows the temperature dependence of the dielectric constant, ε , of the three $ABi_2Ta_2O_9$ samples. SrBi₂Ta₂O₉ exhibited typical ferroelectric behavior with a ferroelectric Curie temperature (T_C) of 300 °C. The dielectric constant above T_C obeyed the Curie-Weiss law. And the dielectric constant of CaBi₂Ta₂O₉ gradually increased with increasing temperature but did not show a transition peak up to 600 °C. The measurement of ε above 600 °C was, however, unsuccessful because dielectric loss increased owing to a conducting property of the sample. Since the ferroelectric state of CaBi₂Ta₂O₉ at room temperature was confirmed by a *P*-*E* hysteresis measurement, the Curie temperature of CaBi₂Ta₂O₉ should be over 600 °C. In the plot of ε against

TABLE I. Refined structural parameters of CaBi₂Ta₂O₉. Numbers in parentheses are standard deviations of the last significant digit. B_{eq} is the equivalent isotropic thermal parameter obtained from refined anisotropic thermal parameters. No vacancies were detected at all the sites, and, therefore, all the occupation factors were fixed at 1. Space group; $A2_1am$. a=5.4625(1) Å, b=5.4286(1) Å, and c=24.9450(6) Å. $R_{wp}=3.70\%$, $R_p=2.82\%$, $R_I=0.80\%$, $R_F=0.54\%$, and $R_e=2.79\%$.

Atom	Position	x	у	Z	g	$B_{\rm eq}$ (Å ²)
Ca	4a	0	0.2484(11)	0	1	0.43
Bi	8 <i>b</i>	0.4865(15)	0.7749(4)	0.198 94(8)	1	1.00
Та	8 <i>b</i>	0.5285(15)	0.7510(7)	0.416 80(7)	1	0.10
O(1)	4a	0.5575(19)	0.3175(10)	0	1	0.98
O(2)	8 <i>b</i>	0.5299(17)	0.6800(7)	0.344 39(11)	1	0.90
O(3)	8 <i>b</i>	0.7535(16)	0.9952(9)	0.250 25(15)	1	0.84
O(4)	8 <i>b</i>	0.7555(17)	0.9638(8)	0.063 89(14)	1	0.59
O(5)	8 <i>b</i>	0.8423(14)	0.9490(8)	0.585 78(16)	1	0.94

TABLE II. Refined structural parameters of SrBi₂Ta₂O₉: Space group; $A2_1am$. a=5.5224(2) Å, b=5.5241(2) Å, and c=25.0264(5) Å. $R_{wp}=4.90\%$, $R_p=3.73\%$, $R_I=1.37\%$, $R_F=1.03\%$, and $R_e=4.64\%$.

Atom	Position	x	у	Z	g	$B_{\rm eq}({\rm \AA}^2)$
Sr	4a	0	0.2567(9)	0	1	0.69
Bi	8 <i>b</i>	0.4634(8)	0.7764(6)	0.199 96(7)	1	1.54
Та	8 <i>b</i>	0.5104(13)	0.7480(7)	0.414 82(7)	1	0.39
O(1)	4a	0.5248(14)	0.2892(13)	0	1	1.04
O(2)	8 <i>b</i>	0.5219(12)	0.6990(11)	0.341 87(11)	1	1.55
O(3)	8 <i>b</i>	0.7381(13)	0.9923(8)	0.25076(13)	1	0.85
O(4)	8 <i>b</i>	0.7554(14)	0.9867(8)	0.069 64(10)	1	0.62
O(5)	8 <i>b</i>	0.7909(12)	0.9807(8)	0.583 59(11)	1	0.91

temperature in BaBi₂Ta₂O₉, there was a broad maximum around 60 °C. In addition, ε significantly depended on measured frequency. The *P*-*E* measurement at room temperature did not show an apparent ferroelectric hysteresis loop.

Apparent orthorhombic distortion in BaBi₂Ta₂O₉ was not observed even at low temperatures. X-ray diffraction peaks measured at -250 °C could be indexed on the basis of the pseudotetragonal cell. Both the full width at half maximum of the 1 1 0 reflection and the intensity ratio of $I(1 \ 1 \ 0)/I(0 \ 0 \ 10)$ remained unchanged over the measured temperature range. (The 1 1 0 reflection in the tetragonal structure should split into two peaks in the orthorhombic structure.) As shown in Fig. 3, no anomalous changes were observed in the plots of lattice parameters *a* and *c* against temperature. The lattice parameters *c* decreased smoothly by about -0.19% over the measured temperature range, but *a* decreased only slightly by about -0.03%.

IV. DISCUSSION

We first discuss the structural and ferroelectric properties of BaBi₂Ta₂O₉. The refined crystal structure of BaBi₂Ta₂O₉ resulted in a pseudotetragonal cell without apparent displacive orthorhombic distortion. Further, no ferroelectric polarization was found in the *P*-*E* hysteresis measurement at room temperature. However, the temperature dependence of the dielectric constant showed the broad peak around 60 °C, suggesting a ferroelectric transition. This kind of broad transition peaks in ε are often observed in relaxor-type ferroelectric materials such as PbMg_{1/3}Nb_{2/3}O₃.¹³ In these materials, microscopic ferroelectric domains have slightly different *T*_C values, which cause gradual ferroelectric transition as indicated by the broad peak in the plot of temperature dependence of dielectric constant. The significant frequency dependence of ε is also a characteristic feature of the relaxortype ferroelectrics. It is, therefore, reasonable to conclude that the observed broad peak in ε of BaBi₂Ta₂O₉ corresponds to a relaxor-type ferroelectric transition. The transition temperature quite close to room temperature appears to explain why no apparent ferroelectric hysteresis loop was observed at room temperature.

The diffraction pattern of $BaBi_2Ta_2O_9$ exhibiting the pseudotetragonal unit cell must reflect the "averaged" structure; that is, the $BaBi_2Ta_2O_9$ structure consists of microdomains with orthorhombic distortion, which causes the relaxor-type ferroelectric transition. The anisotropic peak broadening and the large thermal parameters revealed in the structure refinement based on the macroscopic *I4/mmm* tetragonal symmetry also result from the microscopic structural distortion.

We next discuss structural features of $ABi_2Ta_2O_9$. As shown in Fig. 4, lattice parameters increased as the size of the A-site cation increased. Orthorhombicity, 2(a-b)/(a + b), decreased with increasing size of the A-site cation. The structural distortion is explained in terms of a lattice mismatch between TaO₂ and AO planes in the perovskite-type unit of ATa₂O₇. In a purely ionic model, tolerance factor, *t*, for the perovskite structure is given by

$$t = (r_A + r_O) / \sqrt{2} (r_B + r_O), \tag{1}$$

TABLE III. Refined structural parameters of BaBi₂Ta₂O₉: Space group; *I*4/*mmm*. *a*=3.926 50(8) Å and *c*=25.5866(8) Å. R_{wp} =4.79%, R_p =3.55%, R_I =1.93%, R_F =1.85%, and R_e =2.93%.

Atom	Position	x	у	Z	g	$B_{\rm eq}({\rm \AA}^2)$
Ba	2a	0	0	0	1 ^a	0.85
Bi	4e	0	0	0.201 87(19)	1 ^a	2.70
Та	4e	0	0	0.412 00(13)	1	0.31
O(1)	2b	0	0	1/2	1	1.45
O(2)	4e	0	0	0.340 32(18)	1	2.30
O(3)	4d	0	1/2	1/4	1	0.93
O(4)	8g	0	1/2	0.421 27(14)	1	0.99

^aSubstitution between Ba and Bi ions might occur (see text).



FIG. 2. Temperature dependence of the dielectric constant ε of $ABi_2Ta_2O_9$ (A=Ca, Sr, and Ba). The data of $BaBi_2Ta_2O_9$ measured with different frequencies from 1 to 100 kHz are also shown.

where r_A , r_B , and r_O are ionic radii of an A-site cation, a *B*-site cation, and an oxygen ion, respectively.¹⁴ If we apply this relation to the perovskite-type unit of $ABi_2Ta_2O_9$, the tolerance factors are those listed in Table IV. Note that t's of orthorhombic CaBi₂Ta₂O₉ and SrBi₂Ta₂O₉ are less than 1 while t of pseudotetragonal $BaBi_2Ta_2O_9$ is more than unity. This means that, in the orthorhombic structure, the TaO_2 plane is under compressive stress while the AO plane is under tensile stress. This type of lattice mismatch usually causes cooperative rotations of BO₆ octahedra, i.e., GdFeO₃-type distortion. In the Bi-layered compounds, however, such cooperative rotations of the octahedra are not allowed owing to the presence of the Bi_2O_2 layers above and below the ATa_2O_7 perovskite-type unit: thus, the octahedron itself is considerably distorted, leading to the $A2_1am$ orthorhombic symmetry.

Figure 5 illustrates the crystal structures of $ABi_2Ta_2O_9$ as projections onto a-b and a-c planes in the orthorhombic cell. The structures were drawn with the refined positional parameters listed in Tables I, II, and III. As clearly seen in the figure, the distortion of the TaO₆ octahedra becomes more pronounced as the size of the A-site cation decreases. Table V lists the selected bond lengths and angles of the



FIG. 3. Changes in the lattice parameters of $BaBi_2Ta_2O_9$ at low temperatures.



FIG. 4. Lattice parameters of $ABi_2Ta_2O_9$ (A=Ca, Sr, and Ba) plotted against the ionic radii of the A^{2+} ions. The pseudotetragonal lattice parameters of $BaBi_2Ta_2O_9$ were converted to the orthorhombic ones.

TaO₆ octahedra and the Bi₂O₂ layers. Four different Ta-O bond lengths in the TaO₂ plane are included in orthorhombic $CaBi_2Ta_2O_9$ and $SrBi_2Ta_2O_9$, though these bonds are equivalent in pseudotetragonal BaBi₂Ta₂O₉. The lengths of these bonds lie between 1.921(6) and 2.049(6) Å in $CaBi_2Ta_2O_9$ and between 1.928(5) and 2.017(5) Å in SrBi₂Ta₂O₉. The difference in the lengths of the longest [one of the Ta-O(4) bonds] and the shortest [one of the Ta-O(5) bonds] bonds is larger in CaBi₂Ta₂O₉ than that in SrBi₂Ta₂O₉. This finding reveals the octahedra in CaBi₂Ta₂O₉ to be more distorted. The TaO₆ octahedra are buckled along the b axis in the orthorhombic Ca and Sr systems. The tilting angles of the octahedra from the c axis obtained from the bond angles of Ta-O(1)-Ta are $10.8(3)^{\circ}~(CaBi_{2}Ta_{2}O_{9}),~6.5(3)^{\circ}~(SrBi_{2}Ta_{2}O_{9}),~and~0^{\circ}$ $(BaBi_2Ta_2O_9)$. Therefore, $CaBi_2Ta_2O_9$ is the most structurally distorted. Since the lattice mismatch between the TaO₂ and AO planes in the octahedral unit of CaBi₂Ta₂O₉ is expected to be the most pronounced among the three $ABi_{2}Ta_{2}O_{9}$ compounds as indicated by the smallest t value, the observed largest distortion of the octahedra in $CaBi_2Ta_2O_9$ is quite reasonable.

In the $A2_1am$ orthorhombic structure, atomic displacements along the *a* axis from the corresponding positions in the parent tetragonal structure produce spontaneous ferroelectric polarization. By setting the position of the *A* site at the origin, Fig 6(a), illustrates atomic displacements along the *a* axis of each constituent ion in CaBi₂Ta₂O₉ and SrBi₂Ta₂O₉. No ions in pseudotetragonal BaBi₂Ta₂O₉ are displaced in such ways; thus, the positions of the ions are

TABLE IV. Ionic radii (Å) of A^{2+} ions coordinated to 12 oxygen ions and tolerance factors, *t*, for the ATa_2O_7 perovskite-type units. Ionic radii of Ta^{5+} coordinated to 6 oxygen ions and O^{2-} are 0.64 and 1.40 Å, respectively.

	Ca	Sr	Ba
ionic radius	1.34	1.44	1.61
t	0.95	0.98	1.04



FIG. 5. Crystal structures of $ABi_2Ta_2O_9$ (A=Ca, Sr, and Ba) drawn with the positional parameters refined with the neutron-diffraction data.

located on a solid line in the center. The displacements along the *a* axis in the orthorhombic structure show that the Bi₂O₂ layers and the ATa_2O_7 perovskite-type units shift in opposite directions. It is notable that the ions, particularly Ta⁵⁺, $O(1)^{2-}$, and $O(5)^{2-}$ in the ATa_2O_7 unit of CaBi₂Ta₂O₉, are more displaced than those of SrBi₂Ta₂O₉. The Bi³⁺ ion in the Bi₂O₂ layer, on the other hand, is more displaced in SrBi₂Ta₂O₉.

From the atomic displacements, we can calculate the total polarization of the displacive-type ferroelectric $CaBi_2Ta_2O_9$ and $SrBi_2Ta_2O_9$ as

$$P_{s} = \sum_{i} (m_{i} \times \Delta x_{i} \times Q_{i}e) / V, \qquad (2)$$

where m_i is the site multiplicity, Δx_i is the atomic displacement along the *a* axis from the corresponding position in the

TABLE V. Selected bond lengths (Å) and angles (°) of $ABi_2Ta_2O_9$ (A=Ca, Sr, and Ba).

	CaBi ₂ Ta ₂ O ₉	SrBi ₂ Ta ₂ O ₉	BaBi ₂ Ta ₂ O ₉
Bi-O(3)	2.280(6)	2.311(4)	2.317(2) (×4)
	2.194(6)	2.190(4)	
	2.458(6)	2.507(4)	
	2.318(6)	2.296(4)	
Ta-O(1)	2.113(2)	2.145(2)	2.256(3)
Ta-O(2)	1.847(3)	1.847(3)	1.822(6)
Ta-O(4)	1.954(7)	1.953(5)	1.9786(6) (×4)
	2.049(6)	2.017(5)	
Ta-O(5)	1.921(6)	1.928(5)	
	2.024(6)	2.013(5)	
Ta-O(1)-Ta	158.5(3)	167.1(3)	180
TaO_6 tilting	10.8	6.5	0



FIG. 6. Schematic drawings of (a) atomic displacements (fraction of the *a* axis length) and (b) contributions to the total ferroelectric polarization (μ C/cm²) of each ion of CaBi₂Ta₂O₉ (closed arrows) and SrBi₂Ta₂O₉ (open arrows). The position of the *A* site on the *a* axis is fixed at the origin.

tetragonal structure, $Q_i e$ is the ionic charge of the *i*th constituent ion, and V is the unit-cell volume. The contributions of each constituent ion to the total ferroelectric polarization are shown in Fig. 6(b). The polarizations of CaBi₂Ta₂O₉ and SrBi₂Ta₂O₉ were calculated at 20.6 and 18.2 μ C/cm², respectively. In CaBi₂Ta₂O₉, the large atomic displacement of the O(5)²⁻ ion in the TaO₆ octahedron plays a major role in the marked ferroelectric polarization. The large atomic displacement of the Bi³⁺ ion also contributes greatly to the spontaneous ferroelectric polarization of SrBi₂Ta₂O₉.

V. SUMMARY

We synthesized a series of Bi-layered compounds, CaBi₂Ta₂O₉, SrBi₂Ta₂O₉, and BaBi₂Ta₂O₉, and examined their crystal structures and ferroelectric properties. The structure analysis by neutron diffraction revealed that the structures of ferroelectric CaBi₂Ta₂O₉ ($T_{\rm C}$ >600 °C) and $SrBi_2Ta_2O_9$ ($T_C = 300 \circ C$) are orthorhombic with the $A2_1am$ symmetry, whereas that of BaBi₂Ta₂O₉ is pseudotetragonal (14/mmm). The macroscopic pseudotetragonal structure of BaBi2Ta2O9 consists of microdomains with orthorhombic distortion, which causes the relaxor-type ferroelectric transition around 60 °C. The structural distortion is well explained in terms of the lattice mismatch between the TaO₂ and AO planes, where the mismatch is estimated by the tolerance factor for the perovskite-type unit. As the size of the A-site cation decreases from Ba^{2+} to Ca^{2+} , the lattice mismatch increases (t decreases), and the structural distortion becomes more pronounced. This pronounced distortion leads to the higher Curie temperature and the larger spontaneous ferroelectric polarization. This finding is consistent with our previous observation in the stoichiometric SrBi₂Ta₂O₉ and the off-stoichiometric Sr_{0.8}Bi_{2.2}Ta₂O₉; that is, substitution of smaller Bi^{3+} ions for Sr^{2+} ions at the Sr site increases structural distortion, leading to larger ferroelectric polarization and higher ferroelectric Curie temperature.

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